

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L22	18936	(MSQ or HSQ or methylsilsesquioxane or silsesquioxane or dielectric or (low adj k)) same (porous or pore or void)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2005/06/25 18:33
L23	1521	22 and (((electron or e ²) near5 (beam or ray or irradiat\$6)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2005/06/25 18:34
L24	1308	23 and (semiconductor or interconnect\$6 or wiring or Cu or copper or damascene or dualdamascene)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2005/06/25 18:34
L25	1262	24 and (@ad<="20031106" or @rlad<="20031126")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2005/06/25 18:34
L26	346	25 and (((electron or e ²) near5 (beam or ray or irradiat\$6)) same (pores or porous or void or space))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2005/06/25 18:35

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L8	983	(MSQ or HSQ or methylsilsesquioxane or silsesquioxane) same (porous or pore or void)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2005/06/25 14:52
L9	178	8 and (((electron or e ^{sup} \$2) near5 (beam or ray or irradiat\$6)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2005/06/25 14:52
L10	165	9 and (@ad<="20031106" or @rlad<="20031126")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2005/06/25 14:53
L11	162	10 and (semiconductor or interconnect\$6 or wiring or Cu or copper or damascene or dualdamascene)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2005/06/25 14:53